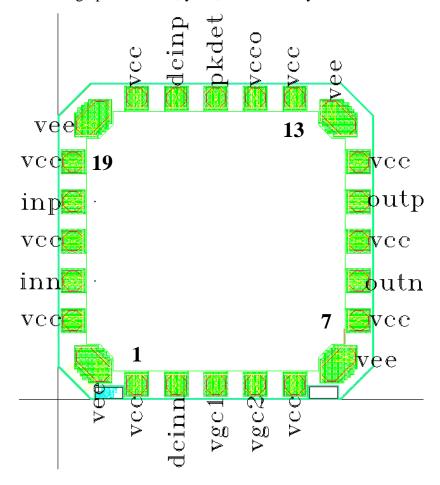
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ASNT6141-BD DC-12GHz Linear amplifier

- Broadband (DC-12*GHz*) linear amplifier for receiver-side applications
- Features controlled gain from 0dB to 31.5dB
- Features input offset adjustment and input peak detector
- Fully differential input interface with on-chip 50*Ohm* termination
- Fully differential output interface with on-chip 50*Ohm* termination
- Output 1dB compression point of 1.5dBm
- 3rd Harmonic better than -47dBc within the full bandwidth
- 15dB Noise Figure
- Single +3.3V or -3.3V power supply
- Power consumption: 530mW typical
- Fabricated in SiGe for high performance, yield, and reliability



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DESCRIPTION

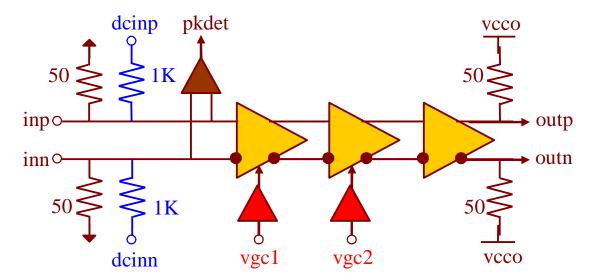


Fig. 1. Functional Block Diagram

The temperature-stable linear amplifier IC shown in Fig. 1 has been fabricated in SiGe technology and provides low-jitter broadband variable signal amplification between its input inp/inn and output outp/outn signal ports. This IC is intended for use in high-speed communication systems. The gain adjustment is performed through two independent external control ports vgc1 and vgc2. The typical gain control characteristic is shown in Fig. 2.

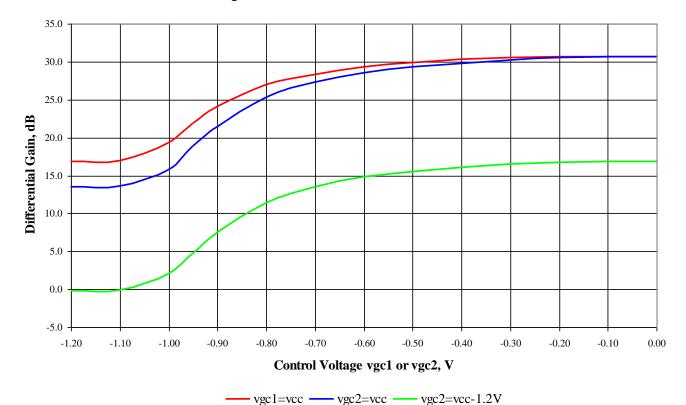


Fig. 2. Typical Gain Control Characteristic



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The part's I/Os support the CML logic interface with on chip 50*Ohm* termination to vcc and may be used differentially, AC/DC coupled, single-ended, or in any combination (see also POWER SUPPLY CONFIGURATION). In the DC-coupling mode, the input signal's common mode voltage should comply with the specifications shown in ELECTRICAL CHARACTERISTICS. In the AC-coupling mode, the input termination provides the required common mode voltage automatically. The differential DC signaling mode is recommended for optimal performance.

The on-chip peak detector delivers a single-ended output voltage **pkdet** reverse-proportional to the input signal's amplitude. A typical dependence of the **pkdet** output voltage versus single-ended input peak-to-peak swing is shown in Fig. 3.

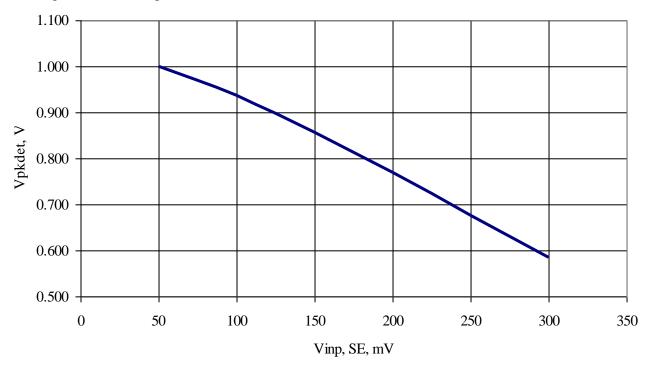


Fig. 3. Typical Peak Detector Output Characteristic

Additional control ports dcinp and dcinn can be used for input signal common-mode voltage adjustment. For the optional output common-mode voltage adjustment, the output termination resistors are connected to a separate positive supply voltage vcco that may be different from vcc.

POWER SUPPLY CONFIGURATION

The part can operate with either a negative supply (vcc = 0.0V=ground and vee = -3.3V), or a positive supply (vcc = +3.3V and vee = 0.0V=ground). In case of the positive supply, all I/Os need AC termination when connected to any devices with 50Ohm termination to ground. Different PCB layouts will be needed for each different power supply combination.

All the characteristics detailed below assume vcc = 0.0V and vee = -3.3V.



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ABSOLUTE MAXIMUM RATINGS

Caution: Exceeding the absolute maximum ratings shown in Table 1 may cause damage to this product and/or lead to reduced reliability. Functional performance is specified over the recommended operating conditions for power supply and temperature only. AC and DC device characteristics at or beyond the absolute maximum ratings are not assumed or implied.

Table 1. Absolute Maximum Ratings

Parameter	Min	Max	Units
Main Supply Voltage (vcc-vee)		3.6	V
Output Supply Voltage (vcco-vcc)	-0.8	+0.8	V
Power Consumption		0.60	W
RF Input Voltage Swing (SE)		1.0	V
Control Voltages (vgc1-vcc, vgc2-vcc)	-2.0	+0.4	V
Case Temperature		+90	°C
Storage Temperature	-40	+100	°C
Operational Humidity	10	98	%
Storage Humidity	10	98	%

TERMINAL FUNCTIONS

TERMINAL		AL	DESCRIPTION			
Name	No.	Type				
High-Speed I/Os						
inp	20	CML	Differential high-speed signal inputs with internal SE 500hm			
inn	22	input	termination to VCC			
outp	10	CML	Differential high-speed signal outputs with internal SE 500hm			
outn	8	output	termination to vcc. Require external SE 50 <i>Ohm</i> termination to vcc			
Low-Speed I/Os						
dcinp	16	Input	inp DC common mode voltage down shift			
dcinn	2	Input	inn common mode control voltage down shift			
vgc1	3	Input	Low-speed amplitude adjustment tuning input			
vgc2	4	Input	Low-speed amplitude adjustment tuning input			
pkdet	15	Output	Peak detector output with on-chip 2.8KOhm termination to vcc			
	Supply and Termination Voltages					
Name	Description		scription	Pin Number		
vcc	vcc Positive power supply $(+3.3V \text{ or } 0V)$		supply $(+3.3V \text{ or } 0V)$	1, 5, 7, 9, 11, 13, 17, 19, 21, 23		
vcco	Output buffer power supply		ffer power supply	14		
vee	Negative power supply $(0V \text{ or } -3.3V)$		r supply (0 <i>V</i> or -3.3 <i>V</i>)	6, 12, 18, 24		



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ELECTRICAL CHARACTERISTICS

PARAMETER	MIN	TYP	MAX	UNIT	COMM	MENTS	
General Parameters							
vee	-3.1	-3.3	-3.5	V	±6%		
vcc		0.0		V	External ground		
Ivee		160	176	mA			
Power consumption		530		mW			
Junction temperature	-25	50	85	$^{\circ}C$			
		HS In	put Data	a (inp/inn)			
Bandwidth		12		GHz	At -3dB level from 24dB gain		
CM level	-0.8		0	V			
Input referred noise density		2.5		<i>nV</i> /sqrt(<i>Hz</i>)	At maximum gain		
S11		-15		dB	DC to 10GHz		
HS Output Data (outp/outn)							
CM level		-0.6		V			
S22		-15		dB	DC to 10GHz		
Small-signal differential	30	31.5	33	dB	At 2GHz, vgc1=vgc2=0V		
gain	-0.2	0	0.2	dB	At 2 <i>GHz</i> , vgc1=vgc2=-1.2 <i>V</i>		
Output referred 1dB compression point		1.5		dBm	Single-Ended, at 10 <i>GHz</i>		
	-45 -40			dBc	<9 <i>GHz</i>	A , 220 IV	
2 nd harmonic				dBc	>9 <i>GHz</i>	At 320mVp-p	
3 rd harmonic	-50			dBc	<9 <i>GHz</i>	output swing, SE	
3 narmonic	-47			dBc	>9 <i>GHz</i>	SE	
Low-Speed Control Input (vgc1, vgc2)							
Voltage range	vcc-1		VCC	V			
Input impedance		2		KOhm	Terminated to vcc		
Low-Speed Control Input (dcinp, dcinn)							
Voltage range	vcc-2		VCC	V			
Input impedance		1		KOhm	Terminated to corresponding data inputs		

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DIE INFORMATION

The die has external dimensions of $1.2x1.2mm^2$ with an approximate thickness of $280\mu m$, and includes 24 octagonal pads: 5 on each side and 4 corner pads. The pad frame parameters are presented in Table 2.

Table 2. Pad Frame Parameters

Pad Type	Metal dimensions, μm	Opening dimensions, μm	Step, µm
Side pad	80x80	74x74	150
Corner pad	155x80	149x74	n/a

The part's identification name is ASNT6141-BD. The first 8 characters of the name before the dash identify the bare die including general circuit family, fabrication technology, specific circuit type, and part version while the 2 characters after the dash mark the part as a bare die.

This device complies with the Restriction of Hazardous Substances (RoHS) per 2011/65/EU for all ten substances.

REVISION HISTORY

Revision	Date	Changes
1.1.2	05-2020	Updated Die Information
1.0.2	07-2019	Updated Letterhead
1.0.1	10-2018	First release